

3A, 20V - 40V Schottky Barrier Rectifier

FEATURES

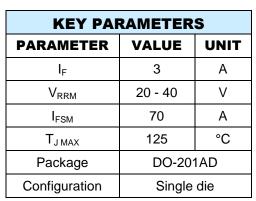
- AEC-Q101 qualified available
- Low forward voltage drop
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converter

MECHANICAL DATA

- Case: DO-201AD
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 1.10g (approximately)











DO-201AD



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	1N5820	1N5821	1N5822	UNIT	
Marking code on the device		1N5820	1N5821	1N5822		
Repetitive peak reverse voltage	V_{RRM}	20	30	40	V	
Reverse voltage, total rms value	$V_{R(RMS)}$	14	21	28	V	
Forward current	I _F	3			А	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	70			А	
Junction temperature	TJ	-55 to +125			°C	
Storage temperature	T _{STG}	-55 to +125			°C	

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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-ambient thermal resistance	R _{eJA}	40	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage ⁽¹⁾	1N5820	I _F = 3A, T _J = 25°C	V _F		0.475	V
	1N5821				0.500	V
	1N5822				0.525	V
Reverse current @ rated V _R ⁽²⁾		T _J = 25°C	1	-	500	μA
		T _J = 100°C	- I _R	-	10	mA
Junction capacitance		1MHz, $V_R = 4.0V$	CJ	200	-	pF

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING		
1N58x	DO-201AD	1,250 / Tape & Reel		
1N58x A0G	DO-201AD	500 / Ammo box		
1N58xH	DO-201AD	1,250 / Tape & Reel		
1N58xHA0G	DO-201AD	500 / Ammo box		

Notes:

- 1. "x" defines voltage from 20V (1N5820) to 40V (1N5822)
- 2. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

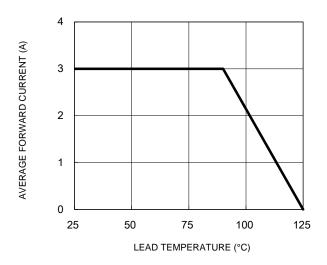


Fig.3 Typical Reverse Characteristics

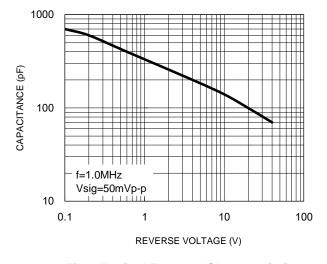
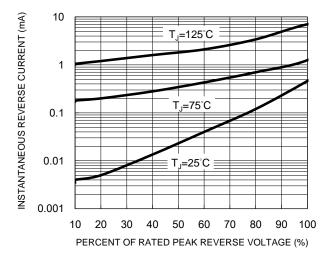


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



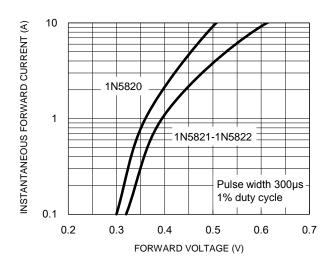
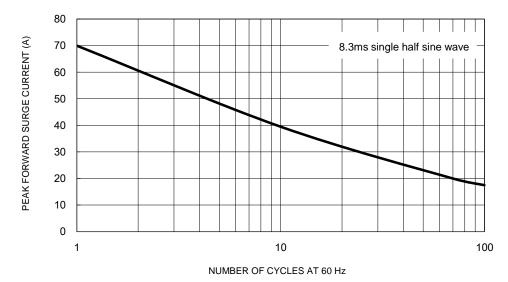


Fig.5 Maximum Non-Repetitive Forward Surge Current

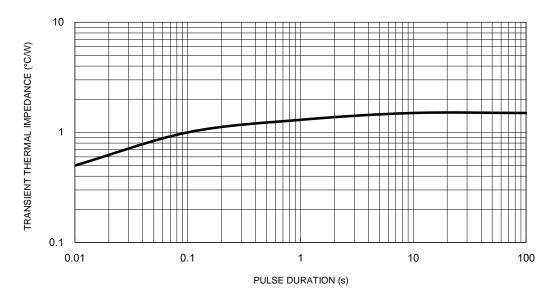


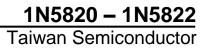


CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

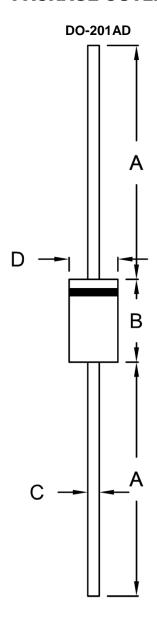
Fig.6 Typical Transient Thermal Characteristics







PACKAGE OUTLINE DIMENSIONS



DIM. Unit (r		(mm)	Unit (inch)		
Dilvi.	Min.	Max.	Min.	Max.	
А	25.40	-	1.000	-	
В	8.50	9.50	0.335	0.374	
С	1.20	1.30	0.047	0.051	
D	5.00	5.60	0.197	0.220	

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code = Factory Code F



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